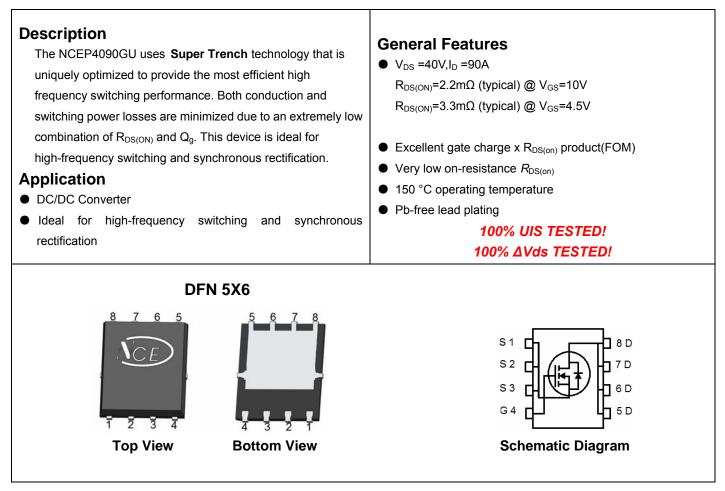




NCE N-Channel Super Trench Power MOSFET



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP4090GU	NCEP4090GU	DFN5x6-8L	-	-	-

Absolute Maximum Ratings (T_c=25[°]C unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	40	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	Ι _D	90	А	
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	63.6	А	
Pulsed Drain Current	I _{DM}	360	А	
Maximum Power Dissipation	PD	70	W	
Derating factor		0.56	W/℃	
Single pulse avalanche energy ^(Note 5)	E _{AS}	500	mJ	
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C	
Thermal Characteristic				
Thermal Resistance, Junction-to-Case ^(Note 2)	R _{θJC}	1.8	°C/W	
Thermal Characteristic		1		





NCEP4090GU

Electrical Characteristics (T_c=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	· · ·		÷			•
Drain-Source Breakdown Voltage	rce Breakdown Voltage BV _{DSS} V _{GS} =0V I _D =250µA		40		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	I					•
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.5	2.0	V
Drain Source On State Desistance		V_{GS} =10V, I _D =20A	-	2.2	2.5	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V_{GS} =4.5V, I _D =20A	-	3.3	3.8	mΩ
Forward Transconductance	g _{FS}	V _{DS} =5V,I _D =20A		60	-	S
Dynamic Characteristics (Note4)	· · ·		÷			•
Input Capacitance	C _{lss}	V _{DS} =20V,V _{GS} =0V,	-	2100	-	PF
Output Capacitance	C _{oss}		-	773	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	15.5	-	PF
Switching Characteristics (Note 4)	I					•
Turn-on Delay Time	t _{d(on)}		-	7.5	-	nS
Turn-on Rise Time	tr	V_{DD} =20V, I_D =20A V_{GS} =10V, R_G =1.6 Ω	-	4.0	-	nS
Turn-Off Delay Time	t _{d(off)}		-	37	-	nS
Turn-Off Fall Time	t _f		-	7.5	-	nS
Total Gate Charge	Qg	V _{DS} =20V,I _D =20A,	-	34.8	-	nC
Gate-Source Charge	Q _{gs}		-	6.2		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	5.1		nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-		1.2	V
Diode Forward Current (Note 2)	I _S		-	-	90	Α
Reverse Recovery Time	t _{rr}	T_J = 25°C, I_F = I_S	-	14	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/ μ s ^(Note3)	-	21	-	nC
						<u> </u>

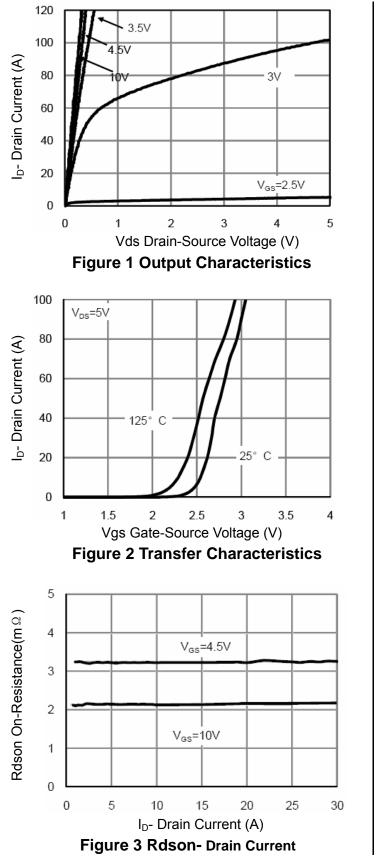
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t \leq 10 sec.
- 3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^\circ \! \mathrm{C}$,V_DD=20V,V_G=10V,L=0.5mH,Rg=25 Ω





Typical Electrical and Thermal Characteristics



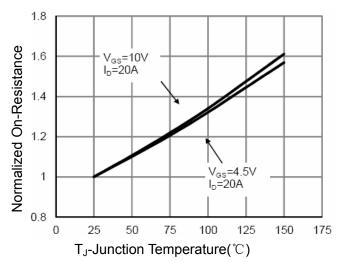


Figure 4 Rdson-Junction Temperature

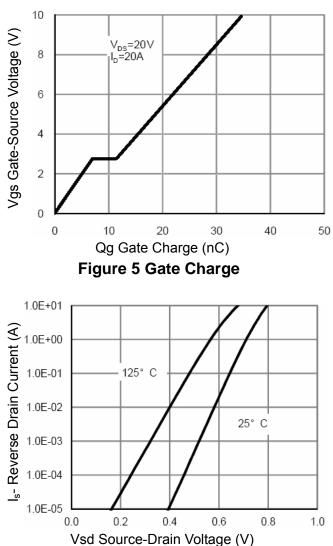
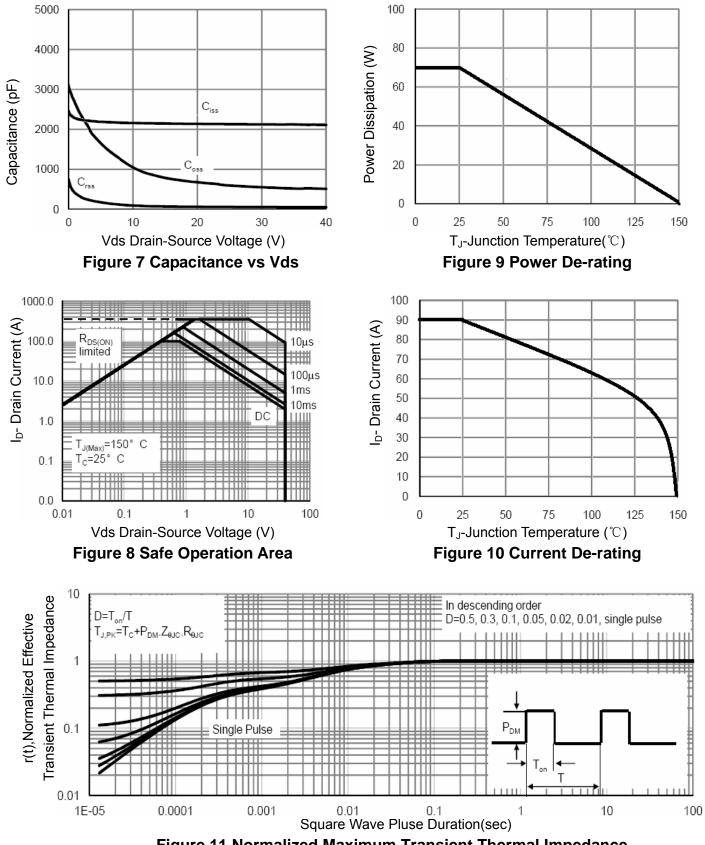


Figure 6 Source- Drain Diode Forward



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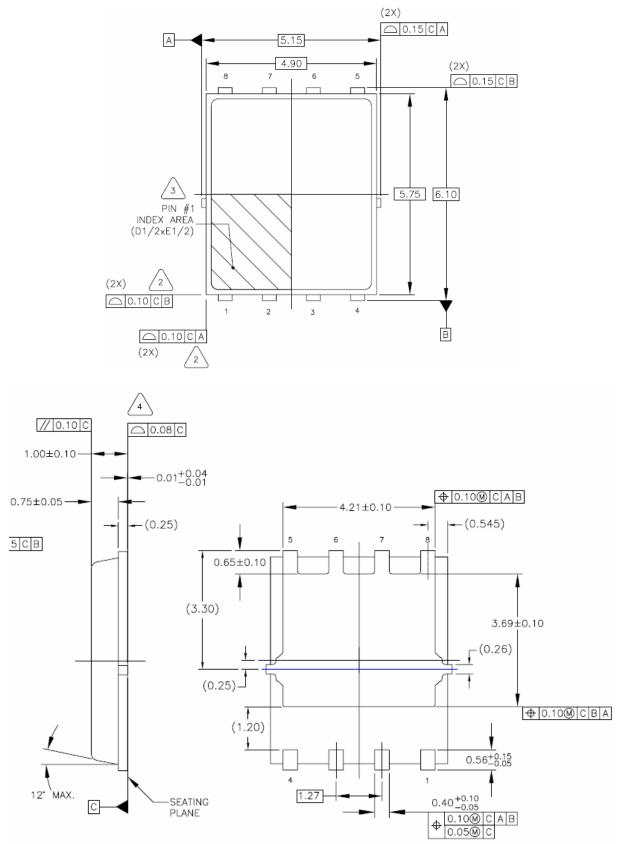




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DFN5X6-8L Package Information







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